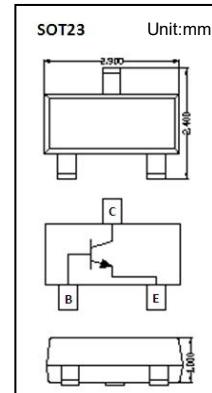


## SOT-23 NPN Transistors

### FEATURES

- ◇ Capable of 500mWatts of Power Dissipation
- ◇ Operating and Storage Junction Temperatures: -55°C to 150°C
- ◇ Surface Mount SOT-23 Package
- ◇ RoHS compliant / Green EMC
- ◇ Collector current: IC=1.0A
- ◇ AEC-Q101 qualified (Automotive grade with suffix " Q".)

Device Marking Code	
FMMT491	491



### Maximum Ratings (Ta=25°C Unless Otherwise Noted)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	80	V
V <sub>CEO</sub>	Collector-Emitter Voltage	60	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	1.0	A
P <sub>D</sub>	Power Dissipation	500	mW
R <sub>θJA</sub>	Thermal Resistance From Junction To Ambient	500	°C/W
T <sub>j</sub>	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55~+150	°C

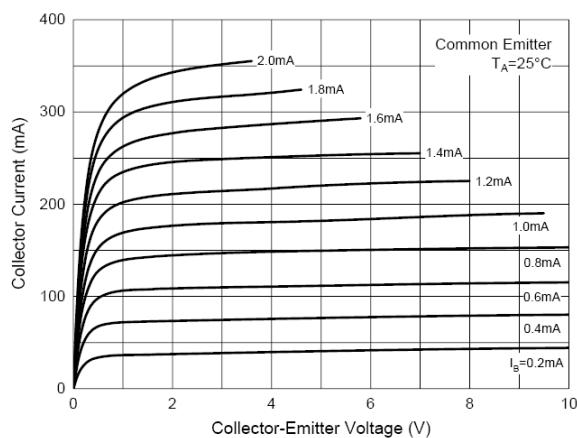
### Electrical Characteristics @ 25° C Unless Otherwise Specified

Symbol	Parameter	Test Conditions		Min	Max	Units
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =0		60		V
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage	I <sub>C</sub> =100μA, I <sub>E</sub> =0		80		V
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage	I <sub>E</sub> =100μA, I <sub>C</sub> =0		5.0		V
I <sub>CBO</sub>	Collector-Base Cutoff Current	V <sub>CB</sub> =60V, I <sub>E</sub> =0			0.1	uA
I <sub>EBO</sub>	Emitter-Base Cutoff Current	V <sub>EB</sub> =4V, I <sub>C</sub> =0			0.1	uA
h <sub>FE</sub>	DC current gain	h <sub>FE(1)</sub>	I <sub>C</sub> =1.0mA, V <sub>CE</sub> =5V*	100		
		h <sub>FE(2)</sub>	I <sub>C</sub> =500mA, V <sub>CE</sub> =5V*	100	300	
		h <sub>FE(3)</sub>	I <sub>C</sub> =1.0A, V <sub>CE</sub> =5V*	80		
		h <sub>FE(4)</sub>	I <sub>C</sub> =2.0A, V <sub>CE</sub> =5V*	30		

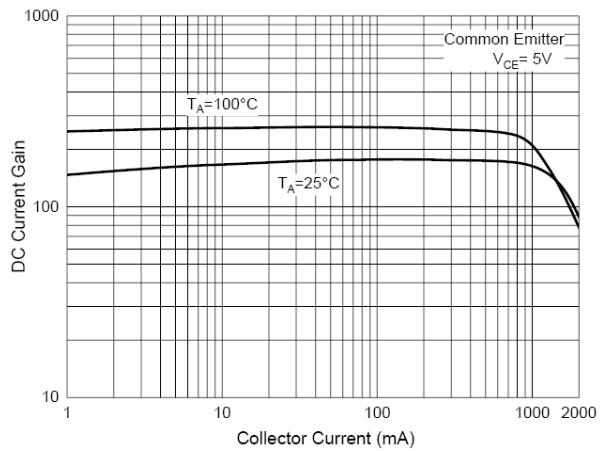
$V_{CE(sat)}$	Collector-emitter saturation voltage	$I_C=500\text{mA}, I_B=50\text{mA}$		0.25	V
		$I_C=1\text{A}, I_B=100\text{mA}$		0.5	
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C=1\text{A}, I_B=100\text{mA}$		1.1	V
$V_{BE}$	Base-Emitter Voltage	$V_{CE}=5\text{V}, I_C=1\text{A}$		1.0	V
$f_T$	Transition frequency	$I_C=50\text{mA}, V_{CE}=10\text{V}, f=100\text{MHz}$	150		MHZ
Cob	Output Capacitance	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$		10	pF

\* Measured under pulsed conditions. Pulse width=300us. Duty cycle 2%

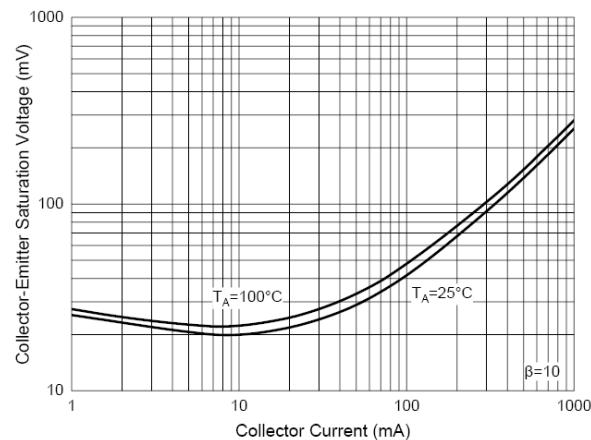
### Typical Characteristics



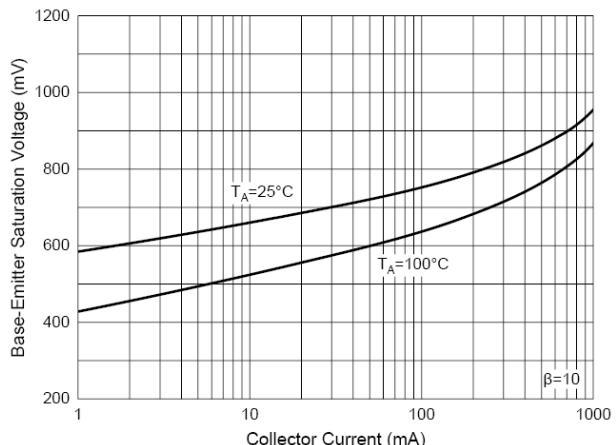
Static Characteristics



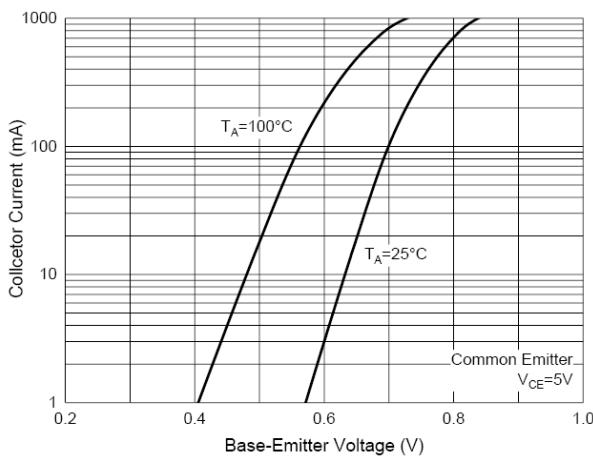
DC Current Gain Characteristics



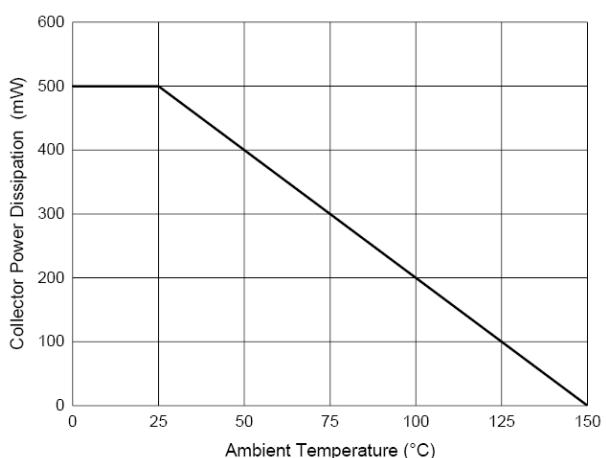
Collector-Emitter Saturation Voltage Characteristics



Base-Emitter Saturation Voltage Characteristics



Base-Emitter Voltage Characteristics

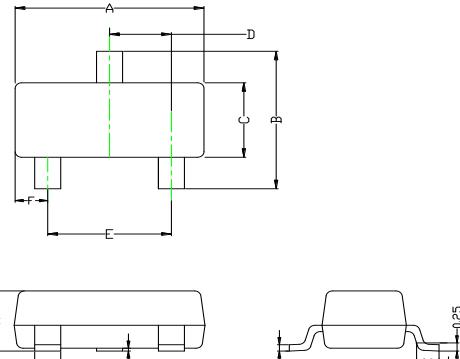
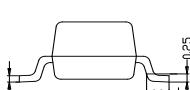


Collector Power Derating Curve

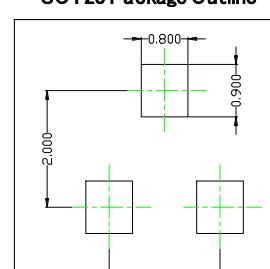
**Ordering Information**

Device	Package	Shipping	Tape wide	Emboss pitch	Tape specification	Notes
FMMT491	SOT23	Tape & Reel 3000pcs /7" Reel	8mm	4mm	Conductive	

**Package Dimensions**

Package outline : SOT23		
		
Symbol	Dimensions in mm	
	Min.	Max.
A	2.800	3.040
B	2.100	2.640
C	1.200	1.400
D	0.890	1.030
E	1.780	2.050
F	0.450	0.600
G	0.013	0.100
H	0.900	1.110
J	0.085	0.180
K	0.370	0.510
L	0.300	0.500

SOT23 Package Outline		
		

Land Pattern Recommendation		